

DMP3035SFG

#### 30V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
	20mΩ @ V <sub>GS</sub> = -10V	-9.5A
-30V	29mΩ @ V <sub>GS</sub> = -5V	-8.5A

### **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

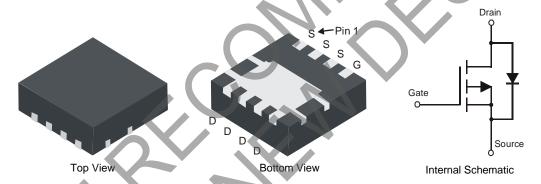
- Backlighting
- Power Management Functions
- DC-DC Converters

#### **Features and Benefits**

- Low R<sub>DS(ON)</sub> Ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free, "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: PowerDI 3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
  Terminals: Finish Matte Tin Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208(3)
- Weight: 0.072 grams (Approximate)



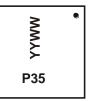
#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3035SFG-7	PowerDI3333-8	2000/Tape & Reel
DMP3035SFG-13	PowerDI3333-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



P35 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



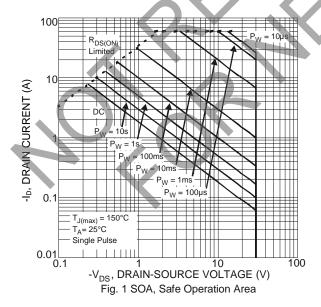
#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

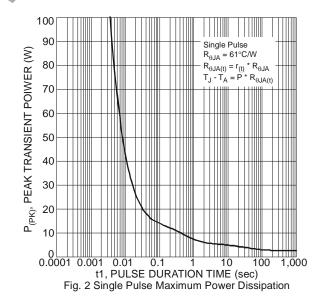
Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-30	V		
Gate-Source Voltage	V <sub>GSS</sub>	±25	V		
Continuous Dusin Compant (Nata C) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-9.5 -6.7	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	t < 10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-12.5 -10.0	Α
Continuous Drain Current (Note 6) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-7.0 -5.5	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = -5V	t < 10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-10.0 -8.0	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-70	А		
Maximum Continuous Body Diode Forward Current	Is	-3.6	Α		

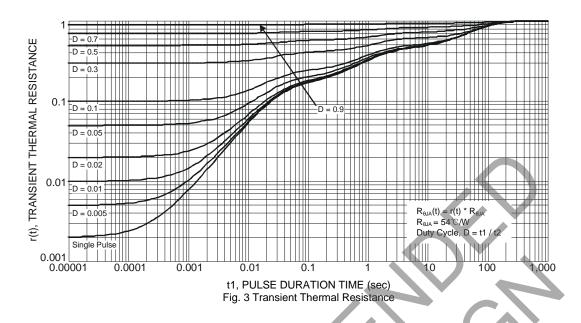
#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.95	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	135	°C/W
Thermal Resistance, Junction to Ambient (Note 3)	t < 10s	$R_{\theta}$ JA	65	°C/W
Total Power Dissipation (Note 6)		P <sub>D</sub>	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	P	55	°C/W
Thermal Resistance, Junction to Ambient (Note 0)	t < 10s	$R_{\theta JA}$	26	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta}$ JC	6.14	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.







## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

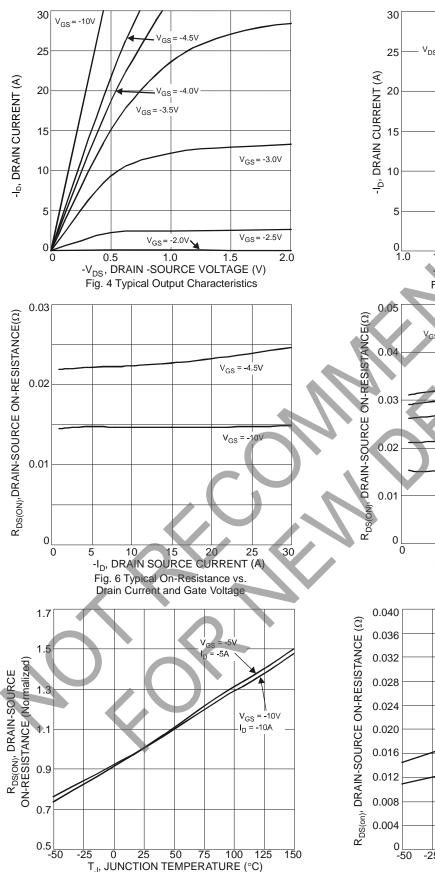
Characteristic		Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		-30		_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	4		-1.0	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	Igss			±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.0	-1.7	-2.5	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	15	20	mΩ	$V_{GS} = -10V, I_D = -8A$	
Static Drain-Source Off-Resistance	R <sub>DS(ON)</sub>	<b>*</b>	21	29	11122	$V_{GS} = -5V, I_D = -5A$	
Forward Transfer Admittance		<u> </u>	22	-	S	$V_{DS} = -5V, I_{D} = -10.0A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.74	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	1633	_	pF	V 45V V 0V	
Output Capacitance	Coss	_	459	_	pF	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	214	_	pF	1 = 1.0Wi iz	
Gate Resistance	$R_{g}$	_	6.5	13	$\Omega$ $V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$		
Total Gate Charge V <sub>GS</sub> = -4.5V	Qg	_	17	_	nC		
Total Gate Charge V <sub>GS</sub> = -10V	$Q_g$	_	35.5	_	nC	V 45V V 40V L 9A	
Gate-Source Charge	Q <sub>gs</sub>	_	4.6	_	nC	$V_{DS} = -15V, V_{GS} = -10V, I_{D} = -8A$	
Gate-Drain Charge	$Q_{gd}$	_	5.7	_	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	8.5	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	14	_	ns	$V_{GEN} = -10V, V_{DD} = -15V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	50	_	ns	$R_{GEN} = 3\Omega$ , $I_D = -15A$	
Turn-Off Fall Time	t <sub>F</sub>	_	25.8	_	ns		

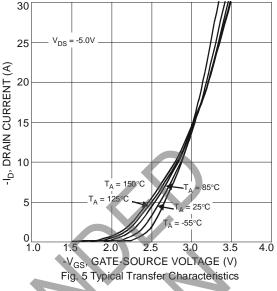
Notes:

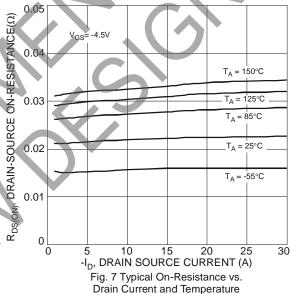
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.



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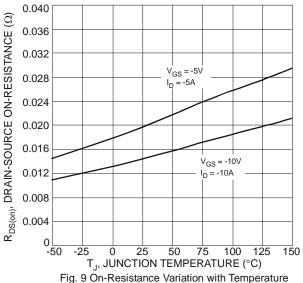


Fig. 8 On-Resistance Variation with Temperature



#### **DMP3035SFG**

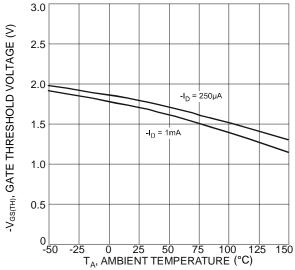
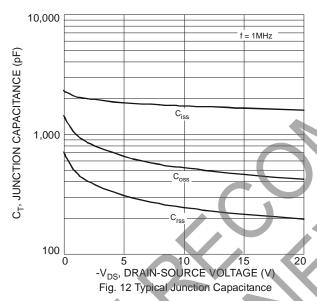
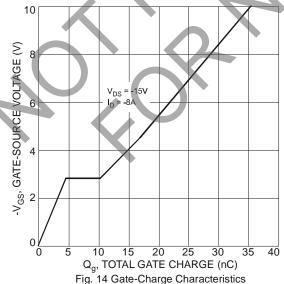


Fig. 10 Gate Threshold Variation vs. Ambient Temperature





30 25 <del>V</del> 20 15 0 0.4 0.6 0.8 1.0 1.2 V<sub>SD</sub>, SOURCE-DRAIN VOLTAGE (V) Fig. 11 Diode Forward Voltage vs. Current

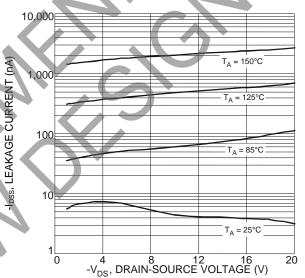


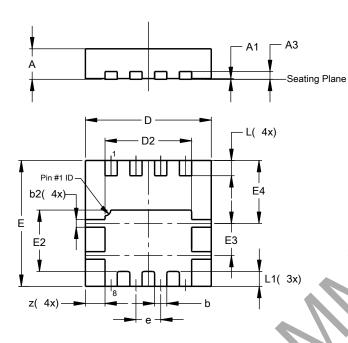
Fig. 13 Typical Drain-Source Leakage Current vs. Voltage



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8

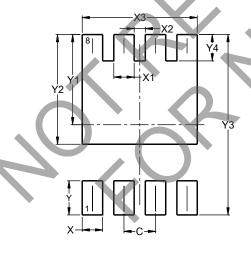


PowerDI3333-8				
Dim	Min	Max	Тур	
Α	0.75	0.85	0.80	
<b>A</b> 1	0.00	0.05	0.02	
A3	_	-	0.203	
b	0.27	0.37	0.32	
b2	0.15	0.25	0.20	
9	3.25	3.35	3.30	
D2	2.22	2.32	2.27	
E	3.25	3.35	3.30	
E2	1.56	1.66	1.61	
E3	0.79	0.89	0.84	
E4	1.60	1.70	1.65	
е		-	0.65	
L	0.35	0.45	0.40	
Į		7	0.39	
Z	-	_	0.515	
All Dimensions in mm				

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
Х3	2.370			
Υ	0.700			
Y1	1.850			
Y2	2.250			
Y3	3.700			
Y4	0.540			



DMP3035SFG

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